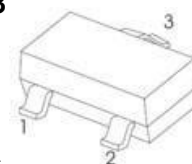


P-Channel 20-V(D-S) MOSFET

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
-20 V	50mΩ@-4.5V	-4A
	60mΩ@-2.5V	
	100mΩ@-1.8V	

SOT-23



- 1. GATE
- 2. SOURCE
- 3. DRAIN

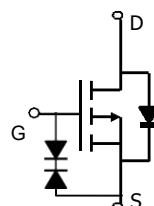
FEATURE

- ⌘ Excellent $R_{DS(ON)}$, low gate charge, low gate voltages
- ⌘ ESD Protected up to 2kV

APPLICATION

- ⌘ Load switch and in PWM applications

Equivalent Circuit



Maximum ratings ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	±8	
Continuous Drain Current ($t \leq 10s$)	I_D	-4.0	A
Maximum Power Dissipation ($t \leq 10s$)	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^{\circ}C/W$
Operating Junction Temperature	T_J	150	$^{\circ}C$
Storage Temperature	T_{STG}	-55 ~ +150	$^{\circ}C$

MOSFET ELECTRICAL CHARACTERISTICS

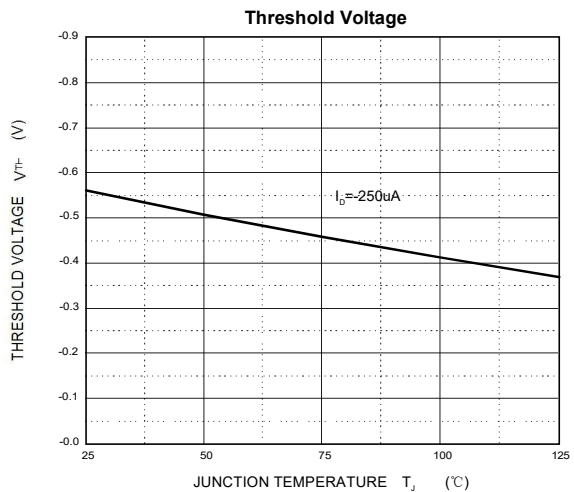
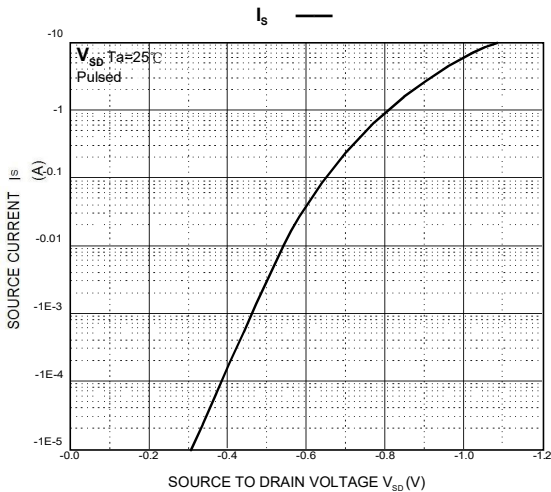
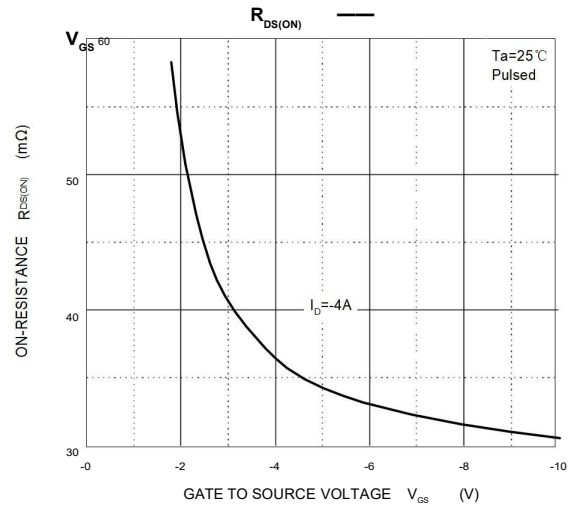
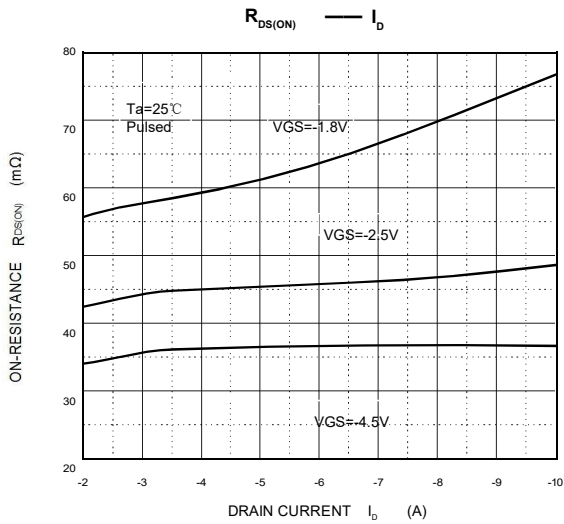
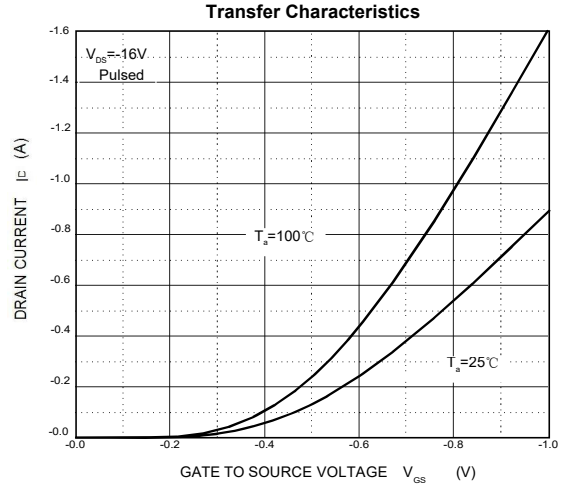
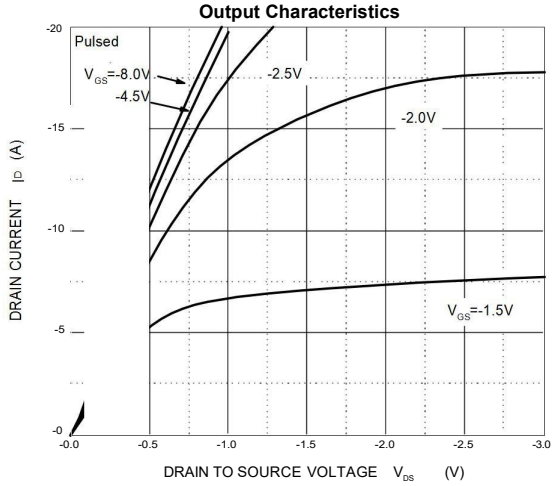
T_a=25 °C unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Static Parameters						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250μA	-20			V
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-0.3	-0.56	-1	
Gate-body leakage current	I _{GSS}	V _{DS} = 0V, V _{GS} = ±8V			±10	μA
		V _{DS} = 0V, V _{GS} = ±4.5V			±1	
Zero gate voltage drain current	I _{DSS}	V _{DS} = -16V, V _{GS} = 0V			-1	
Drain-source on-state resistance(note1)	R _{DS(on)}	V _{GS} = -4.5V, I _D = -4A		0.037	0.050	Ω
		V _{GS} = -2.5V, I _D = -4A		0.045	0.060	
		V _{GS} = -1.8V, I _D = -2A		0.080	0.100	
Forward transconductance(note2)	g _{FS}	V _{DS} = -5V, I _D = -4A	8			S
Body diode voltage(note2)	V _{SD}	I _S = -1A, V _{GS} = 0V			-1	V
Dynamic Parameters (note3)						
Input capacitance	C _{iss}	V _{DS} = -10V, V _{GS} = 0V, f = 1MHz		1450		pF
Output capacitance	C _{oss}			205		
Reverse transfer capacitance	C _{rss}			160		
Gate resistance	R _g	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz		6.5		Ω
Switching Parameters						
Total gate charge	Q _g	V _{DS} = -10V, V _{GS} = -4.5V, I _D = -4A		17.2		nC
Gate-Source charge	Q _{gs}			1.3		
Gate-drain charge	Q _{gd}			4.5		
Turn-on delay time (note3)	t _{d(on)}	V _{DS} = -10V, V _{GS} = -4.5V R _{GEN} = 3Ω, R _L = 2.5Ω,		9.5		ns
Turn-on rise time(note3)	t _r			17		
Turn-off delay time(note3)	t _{d(off)}			94		
Turn-off fall time(note3)	t _f			35		

Notes:

1. Repetitive rating, pulse width limited by junction temperature.
2. Pulse Test : Pulse width ≦ 300μs, duty cycle ≦ 2%.
3. These parameters have no way to verify.

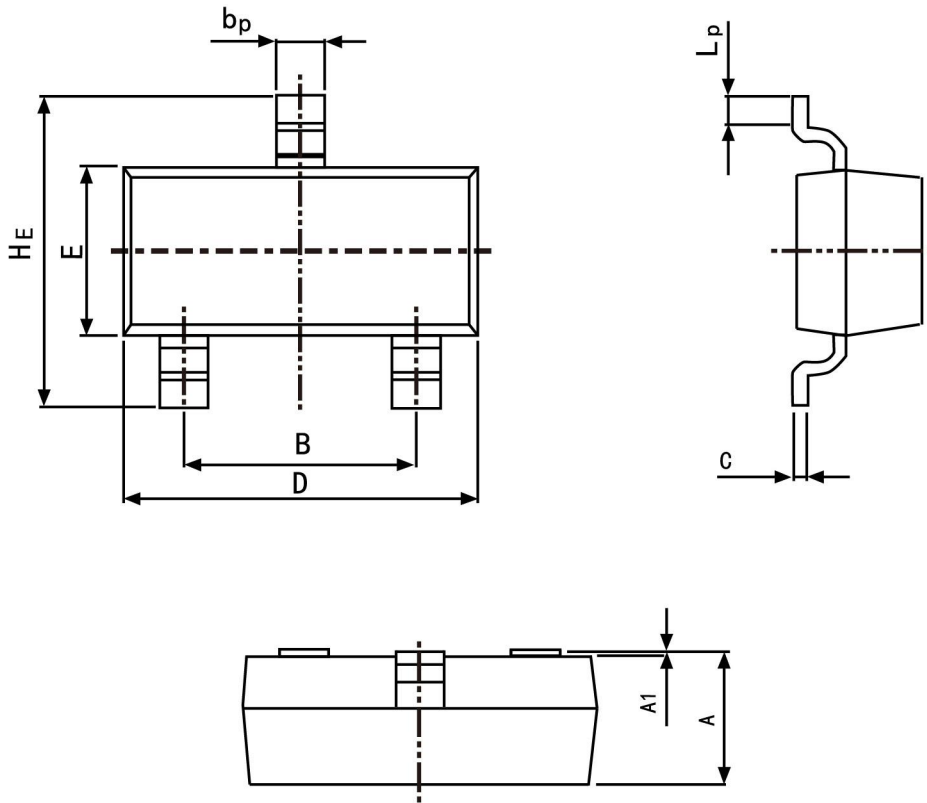
Typical Characteristics



PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

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Symbol	Dimension in Millimeters	
	Min	Max
A	0.95	1.40
B	1.78	2.04
bp	0.35	0.50
C	0.08	0.19
D	2.70	3.10
E	1.20	1.65
HE	2.20	3.00
A1	0.100	0.013
Lp	0.20	0.50

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